

20V P-Channel Enhancement Mode MOSFET - ESD Protected

Voltage -20 V Current -0.6A

Features

- RDS(ON), VGS@-4.5V, ID@-0.6A<340mΩ
- RDS(ON) , VGS@-2.5V, ID@-0.4A<420mΩ
- RDS(ON), VGS@-1.8V, ID@-0.2A<600mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

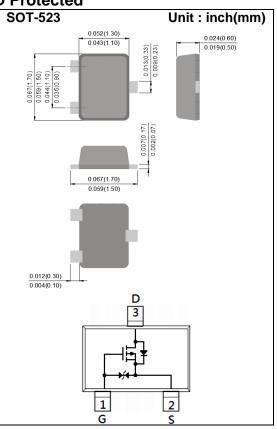
Mechanical Data

• Case: SOT-523 Package

Terminals : Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.002 grams

Marking: E03



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

| PARAMETER | | SYMBOL | LIMIT | UNITS |
|--|----------------------|------------------|------------|-------|
| Drain-Source Voltage | | V _{DS} | -20 | V |
| Gate-Source Voltage | | V _G s | <u>+</u> 8 | V |
| Continuous Drain Current | | ID | -0.6 | Α |
| Pulsed Drain Current | | I _{DM} | -2.4 | Α |
| Power Dissipation | T _a =25°C | _ | 300 | mW |
| | Derate above 25°C | P _D | 2.4 | mW/°C |
| Operating Junction and Storage Temperature Range | | TJ,TSTG | -55~150 | °C |
| Typical Thermal Resistance - Junction to Ambient ^(Note 3) | | Reja | 417 | °C/W |



Electrical Characteristics (T_A=25°C unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS | |
|----------------------------------|---|---|------|--------------|-------------|-------|--|
| Static | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} V _{GS} =0V, I _D =-250uA | | -20 | - | - | V | |
| Gate Threshold Voltage | V _{GS(th)} | V _{DS} =V _{GS} , I _D =-250uA | -0.4 | -0.64 | -1.0 | V | |
| Drain-Source On-State Resistance | R _{DS(on)} | V _{GS} =-4.5V, I _D =-0.6A | - | 280 | 340 | mΩ | |
| | | V _{GS} =-2.5V, I _D =-0.4A | - | 330 | 420 | | |
| | | V _{GS} =-1.8V, I _D =-0.2A | - | 420 | 600 | | |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =-20V, V _{GS} =0V | - | -0.01 | -1 | uA | |
| Gate-Source Leakage Current | Igss | V _{GS} = <u>+</u> 8V, V _{DS} =0V | - | <u>+</u> 3.5 | <u>+</u> 10 | uA | |
| Dynamic | | | | | | | |
| Total Gate Charge | Q_g | | - | 2.2 | - | nC | |
| Gate-Source Charge | Q_{gs} | V _{DS} =-10V, I _D =-0.6A, | - | 0.4 | - | | |
| Gate-Drain Charge | Q_{gd} | V _{GS} =-4.5V ^(Note 1,2) | - | 0.5 | - | | |
| Input Capacitance | Ciss | 101/11/101/ | - | 151 | - | pF | |
| Output Capacitance | Coss | V _{DS} =-10V, V _{GS} =0V, | - | 27 | - | | |
| Reverse Transfer Capacitance | Crss | f=1.0MHZ | - | 9 | - | | |
| Switching | | | | | | | |
| Turn-On Delay Time | td _(on) | \/ 40\/ L 0.04 | - | 9 | - | ns | |
| Turn-On Rise Time | tr | V _{DD} =-10V, I _D =-0.6A, | - | 37 | - | | |
| Turn-Off Delay Time | td _(off) | $V_{GS}=-4.5V$, $R_{G}=6\Omega^{(Note\ 1,2)}$ | - | 128 | - | | |
| Turn-Off Fall Time | tf | KG=012(Note 1,2) | - | 72 | - | | |
| Drain-Source Diode | | | | | | | |
| Maximum Continuous Drain-Source | Is | | _ | | -0.4 | Α | |
| Diode Forward Current | ٥٠ | | | | 0.4 | | |
| Diode Forward Voltage | V _{SD} | Is=-1A, V _{GS} =0V | - | -0.95 | -1.2 | V | |

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited

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TYPICAL CHARACTERISTIC CURVES

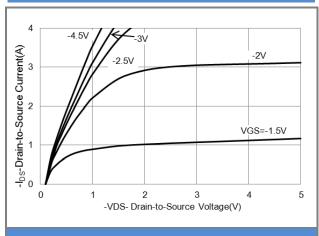


Fig.1 On-Region Characteristics

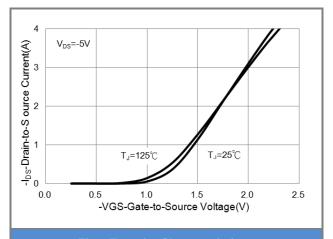


Fig.2 Transfer Characteristics

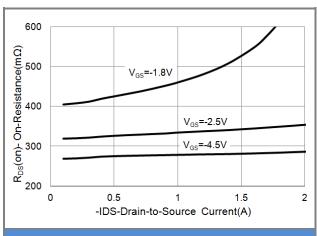


Fig.3 On-Resistance vs. Drain Current

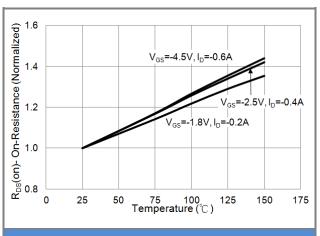
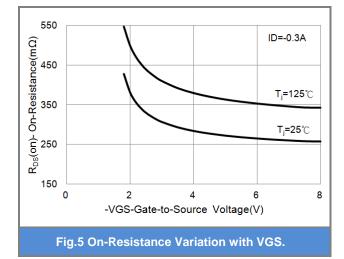
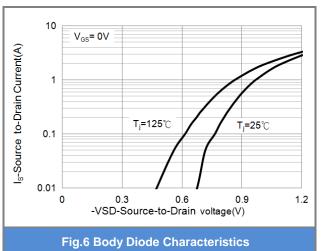


Fig.4 On-Resistance vs. Junction temperature





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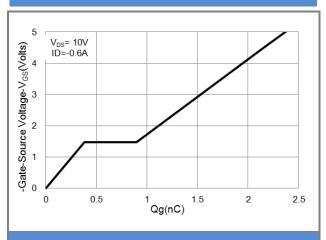


Fig.7 Gate-Charge Characteristics

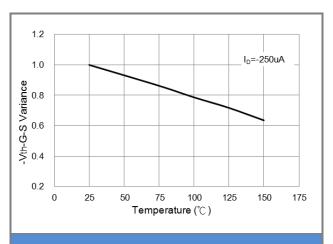


Fig.8 Threshold Voltage Variation with Temperature

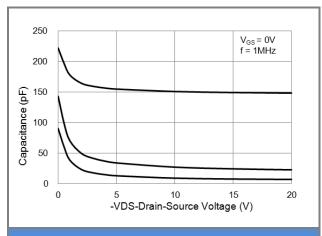


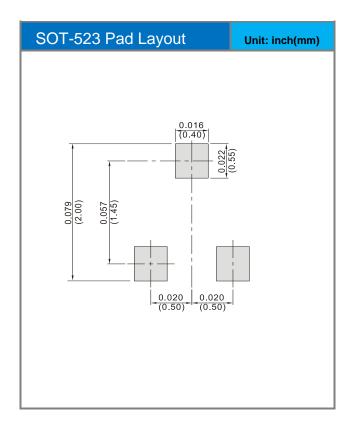
Fig.9 Capacitance vs. Drain-Source Voltage



Product and Packing Information

| Part No. | Package Type | Packing Type | Marking | |
|----------|--------------|------------------|---------|--|
| PJE8403 | SOT-523 | 4K pcs / 7" reel | E03 | |

Mounting Pad Layout



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